TOSHIBA INSULATED GATE BIPOLAR TRANSISTOR SILICON N CHANNEL IGBT

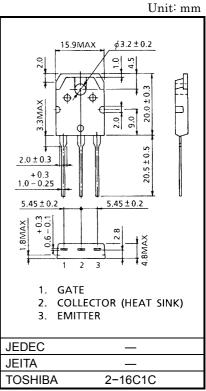
GT30J301

HIGH POWER SWITCHING APPLICATIONS MOTOR CONTROL APPLICATIONS

- The 3rd Generation
- Enhancement–Mode
- High Speed : $t_f = 0.30 \mu s$ (Max.)
- Low Saturation Voltage : V_{CE} (sat) = 2.7V (Max.)
- FRD included between Emitter and Collector

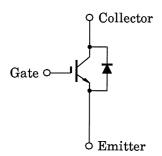
MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	RATING	UNIT	
Collector-Emitter Voltage		V _{CES}	600	V	
Gate-Emitter Voltage		V _{GES}	±20	V	
Collector Current	DC	Ι _C	30	А	
	1ms	I _{CP}	60	А	
Emitter-Collector Forward Current	DC	١ _F	30	А	
	1ms	I _{FM}	60	А	
Collector Power Dissipation (Tc = 25°C)		P _C	155	W	
Junction Temperature		Tj	150	°C	
Storage Temperature Range		T _{stg}	-55~150	°C	



Weight: 4.6g

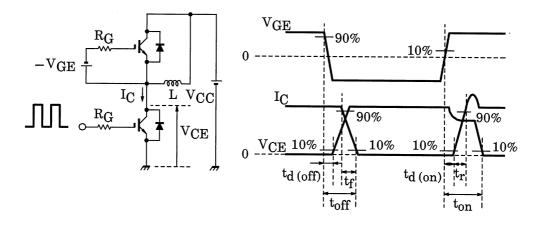
EQUIVALENT CIRCUIT



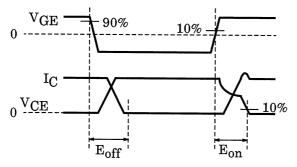
ELECTRICAL CHARACTERISTICS (Ta = 25°C)

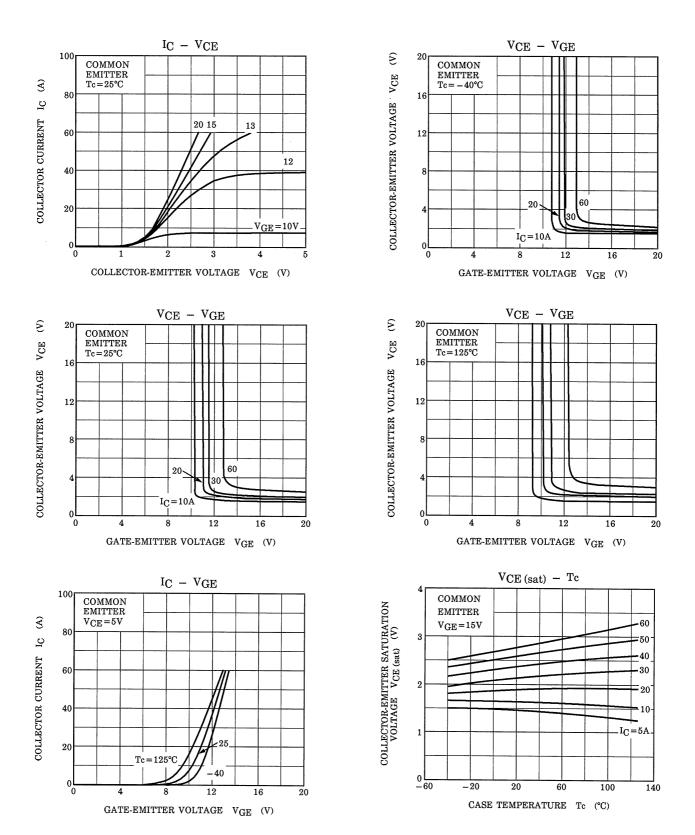
CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT
Gate Leakage Current		I _{GES}	$V_{GE} = \pm 20V, V_{CE} = 0$		—	±500	nA
Collector Cut-Off Current		ICES	V _{CE} = 600V, V _{GE} = 0	_	_	1.0	mA
Gate-Emitter Cut-Off Voltage		V _{GE (OFF)}	I _C = 3mA, V _{CE} = 5V	5.0	_	8.0	V
Collector-Emitter Saturation Voltage		V _{CE (sat)}	I _C = 30A, V _{GE} = 15V	_	2.1	2.7	V
Input Capacitance		C _{ies}	V _{CE} = 20V, V _{GE} = 0, f = 1MHz	_	2200	_	pF
Switching Time	Rise Time	tr	Inductive Load V_{CC} = 300V, I _C = 30A V_{GG} = ±15V, R _G = 43Ω (Note)	-	0.12	_	- µs
	Turn-On Time	t _{on}		-	0.40	_	
	Fall Time	t _f		-	0.15	0.30	
	Turn-Off Time	t _{off}		_	0.70	_	
Peak Forward Voltage		V _F	I _F = 30A, V _{GE} = 0	_	_	2.0	V
Reverse Recovery Time		t _{rr}	I _F = 30A, di / dt = −100A / µs	_	_	200	ns
Thermal Resistance (IGBT)		R _{th (j−c)}	_	_	—	0.81	°C/W
Thermal Resistance (Diode)		R _{th (j−c)}	_	_	—	2.0	°C/W

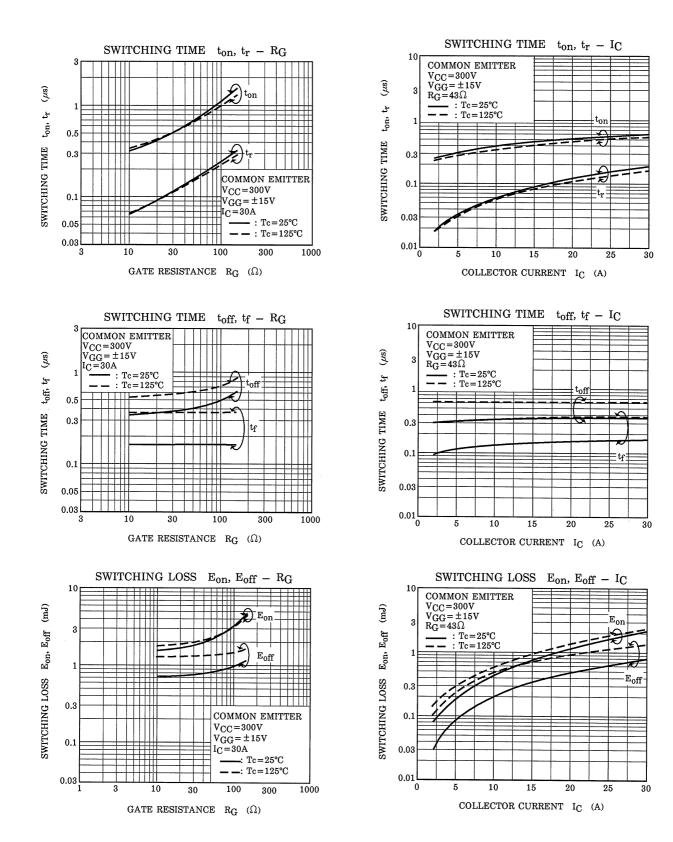
Note : Switching time measurement circuit and input / output waveforms

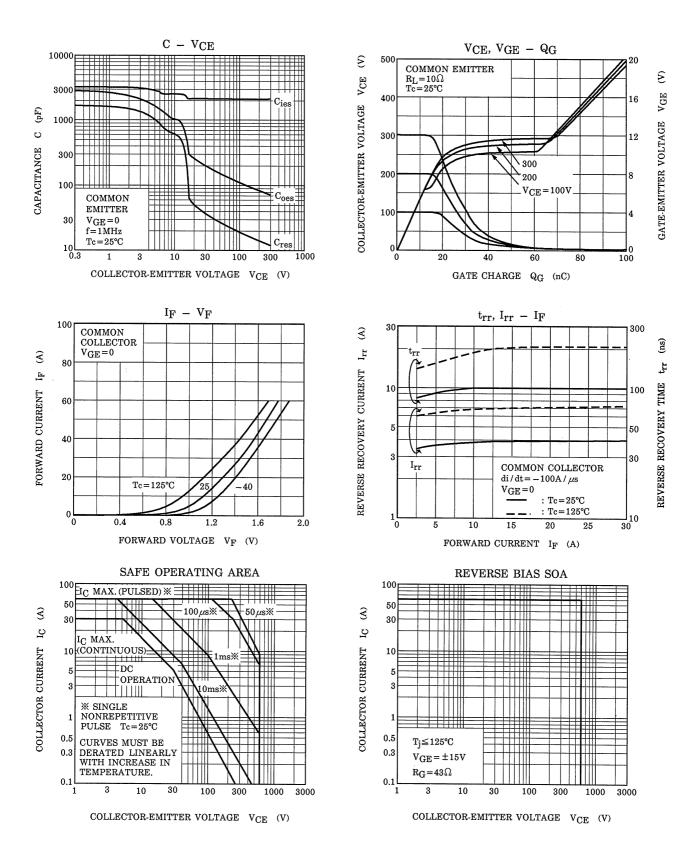


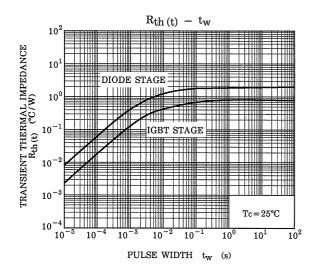
Switching loss measurement waveforms











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